

LMV7271/LMV7275/LMV7272 Single & Dual, 1.8V Low Power Comparators with Rail-to-Rail Input

General Description

The LMV727X are rail-to-rail input low power comparators, which are characterized at supply voltage 1.8V, 2.7V and 5.0V. They consume only 9uA supply current per channel while achieving a 800ns propagation delay.

The LMV7271/LMV7275 (single) are available in SC70 and SOT23 packages. The LMV7272 (dual) is available in micro SMD package. With these tiny packages, the PC board area can be significantly reduced. They are ideal for low voltage, low power and space critical designs.

The LMV7271/LMV7272 both feature a push-pull output stage which allows operation with minimum power consumption when driving a load. The LMV7275 features an open drain output stage that allows for wired-OR configurations. The open drain output also offers the advantage of allowing the output to be pulled to any voltage up to 5.5V, regardless of the supply voltage of the LMV7275.

The LMV727X are built with National Semiconductor's advance submicron silicon-gate BiCMOS process. They all have bipolar inputs for improved noise performance and CMOS outputs for rail-to-rail output swing.

Features

 $(V_S = 1.8V, T_A = 25^{\circ}C, Typical values unless specified).$

- Single or Dual Supplies
- Ultra low supply current 9µA per channel
- Low input bias current 10nA
- Low input offset current 200pA
- Low guaranteed V_{OS} 4mV
 Propagation delay 880ns (20mV overdrive)
- Input common mode voltage range 0.1V beyond rails
- LMV7272 is available in micro SMD package

Applications

- Mobile communications
- Laptops and PDA's
- Battery powered electronics
- General purpose low voltage applications

Typical Circuit

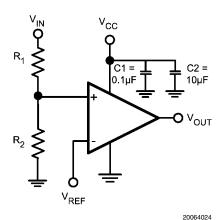


FIGURE 1. Threshold Detector

Part Number	Single/ Dual	Package	Output
LMV7271	Single	SC70,	Push/Pull
		SOT23	
LMV7272	Dual	micro SMD	Push/Pull
LMV7275	Single	SC70,	Open Drain
		SOT23	

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

ESD Tolerance 2KV (Note 2) 200V (Note 6)

V_{IN} Differential ±Supply Voltage

Supply Voltage (V+ - V-) 6V

Voltage at Input/Output pins $V^+ + 0.1V$, $V^- - 0.1V$ Soldering Information

Infrared or Convection (20 sec.) 235°C

Wave Soldering (10 sec.) 260°C Storage Temperature Range -65°C to $+150^{\circ}\text{C}$ Junction Temperature (Note 4) $+150^{\circ}\text{C}$

Operating Ratings (Note 1)

Supply Voltage Range 1.8V to 5.5V Temperature Range (Note 3) -40°C to +85°C

Package Thermal Resistance (Note 3)

 SOT23-5
 325°C/W

 SC-70
 265°C/W

 8-Bump Thin micro SMD
 220°C/W

1.8V Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$, $V^+ = 1.8V$, $V^- = 0V$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Min	Тур	Max	Units
			(Note 5)	(Note 4)	(Note 5)	
Vos	Input Offset Voltage			0.3	4	mV
					6	
TC V _{OS}	Input Offset Temperature Drift	V _{CM} = 0.9V (Note 7)		20		uV/°C
I _B	Input Bias Current			10		nA
I _{os}	Input Offset Current			200		pА
I _S	Supply Current	LMV7271/LMV7275		9	12	
					14	μΑ
		LMV7272		18	25	μA
					28	
I _{SC}	Output Short Circuit Current	Sourcing, V _O = 0.9V	3.5	6		
		(LMV7271/LMV7272 only)				mA
		Sinking, V _O = 0.9V	4	6		
V _{OH}	Output Voltage High	I _O = 0.5mA	1.7	1.74		V
	(LMV7271/LMV7272 only)	I _O = 1.5mA	1.47	1.63		V
V _{OL}	Output Voltage Low	$I_{O} = -0.5 \text{mA}$		52	100	\/
		I _O = -1.5mA		166	220	mV
V _{CM}	Input Common Mode Voltage Range	CMRR > 45 dB			1.9	V
			-0.1			V
CMRR	Common Mode Rejection Ratio	0 < V _{CM} < 1.8V	46	78		dB
PSRR	Power Supply Rejection Ratio	V+ = 1.8V to 5V	55	80		dB
I _{LEAKAGE}	Output Leakage Current	V _O = 1.8V (LMV7275 only)		2		pA

1.8V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$, $V^+ = 1.8V$, $V^- = 0V$, $V_{CM} = 0.5V$, $V_O = V^+/2$ and $R_L > 1M\Omega$ to V^- . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Min	Тур	Max	Units
			(Note 6)	(Note 5)	(Note 6)	
t _{PHL}	Propagation Delay	Input Overdrive = 20mV		880		ns
	(High to Low)	Load = $50pF//5k\Omega$				
		Input Overdrive = 50mV		570		ns
		Load = $50pF//5k\Omega$				
t _{PLH}	Propagation Delay	Input Overdrive = 20mV		1100		ns
	(Low to High)	Load = $50pF//5k\Omega$				
		Input Overdrive = 50mV		800		ns
		Load = $50pF//5k\Omega$				
		Load = $50pF//5k\Omega$				

2.7V Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$, $V^+ = 2.7V$, $V^- = 0V$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
			(Note 6)	(Note 5)	(Note 6)	
V _{OS}	Input Offset Voltage			0.3	4	mV
					6	
TC V _{os}	Input Offset Temperature Drift	V _{CM} = 1.35V (Note 7)		20		μV/°C
I _B	Input Bias Current			10		nA
I _{os}	Input offset Current			200		pА
I _s	Supply Current	LMV7271/LMV7275		9	13	^
					15	μA
		LMV7272		18	25	μΑ
					28	
I _{sc}	Output Short Circuit Current	Sourcing, V _O = 1.35V	12	15		
		(LMV7271/LMV7272 only)				mA
		Sinking, V _O = 1.35V	12	15		
V _{OH}	Output Voltage High	I _O = 0.5mA	2.63	2.66		V
	(LMV7271/LMV7272 only)	I _O = 2.0mA	2.48	2.55		V
V _{OL}	Output Voltage Low	$I_{O} = -0.5 \text{mA}$		50	70	mV
		I _O = -2mA		155	220	
V _{CM}	Input Common Voltage Range	CMRR > 45dB			2.8	V
			-0.1			V
CMRR	Common Mode Rejection Ratio	0 < V _{CM} < 2.7V	46	78		dB
PSRR	Power Supply Rejection Ratio	V+ = 1.8V to 5V	55	80		dB
I _{LEAKAGE}	Output Leakage Current	V _O = 2.7V (LMV7275 only)		2		pА

2.7V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25°C, V^+ = 2.7V, V^- = 0V, V_{CM} = 0.5V, V_O = V+/2 and R_L > 1M Ω to V-. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Min	Тур	Max	Units
			(Note 6)	(Note 5)	(Note 6)	
t _{PHL}	Propagation Delay	Input Overdrive = 20mV		1200		ns
	(High to Low)	Load = $50pF//5k\Omega$				
		Input Overdrive = 50mV		810		ns
		Load = $50pF//5k\Omega$				
t _{PLH}	Propagation Delay	Input Overdrive = 20mV		1300		ns
	(Low to High)	Load = $50pF//5k\Omega$				
		Input Overdrive = 50mV		860		ns
		Load = $50pF//5k\Omega$				

5.0V Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_1 = 25$ °C, $V^+ = 5V$, $V^- = 0V$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
			(Note 6)	(Note 5)	(Note 6)	
V _{os}	Input Offset Voltage			0.3	4	mV
					6	
TC V _{os}	Input Offset Temperature Drift	V _{CM} = 2.5V (Note 7)		20		μV/°C
I _B	Input Bias Current			10		nA
I _{os}	Input Offset Current			200		pA

Symbol	Parameter	Conditions	Min (Note 6)	Typ (Note 5)	Max (Note 6)	Units
I _S	Supply Current	LMV7271/LMV7275		10	14 16	μΑ
		LMV7272		20	27 30	μΑ
I _{SC}	Output Short Circuit Current	Sourcing, $V_O = 2.5V$ (LMV7271/LMV7272 only)	28	34		mA
		Sinking, V _O = 2.5V	28	34		
V _{OH}	Output Voltage High (LMV7271/LMV7272 only)	I _O = 0.5mA	4.93	4.96		V
		I _O = 4.0mA	4.70	4.77		
V _{OL}	Output Voltage Low	$I_{O} = -0.5 \text{mA}$		27	70	\/
		$I_{O} = -4.0 \text{mA}$		225	300	mV
V _{CM}	Input Common Voltage Range	CMRR > 45dB			5.1	V
			-0.1			V
CMRR	Common Mode Rejection Ratio	0 < V _{CM} < 5.0V	46	78		dB
PRSS	Power Supply Rejection Ratio	V+ = 1.8V to 5V	55	80		dB
I _{LEAKAGE}	Output Leakage Current	V _O = 5V (LMV7275 only)		2		pА

5.0V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_J = 25°C, V^+ = 5.0V, V^- = 0V, V_{CM} = 0.5V, V_O = V+/2 and R_L > 1M Ω to V-. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Min	Тур	Max	Units
			(Note 6)	(Note 5)	(Note 6)	
t _{PHL}	Propagation Delay	Input Overdrive = 20mV		2100		ns
	(High to Low)	Load = $50pF//5k\Omega$				
		Input Overdrive = 50mV		1380		ns
		Load = $50pF//5k\Omega$				
t _{PLH}	Propagation Delay	Input Overdrive = 20mV		1800		ns
	(Low to High)	Load = $50pF//5k\Omega$				
		Input Overdrive = 50mV		1100		ns
		Load = $50pF//5k\Omega$				

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

Note 2: Human body model, $1.5k\Omega$ in series with 100pF.

Note 3: The maximum power dissipation is a function of $T_{J(MAX)}$, θ_{JA} , and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)}, -T_A)/\theta_{JA}$. All numbers apply for packages soldered directly into a PC board.

Note 4: Typical values represent the most likely parametric norm.

Note 5: All limits are guaranteed by testing or statistical analysis.

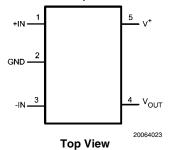
Note 6: Machine Model, 0Ω in series with 200pF.

Note 7: Offset Voltage average drift determined by dividing the change in V_{OS} at temperature extremes into the total temperature change.

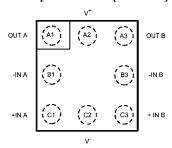
Note 8: Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self heating where $T_J > T_A$. Absolute Maximum Ratings indicate junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.

Connection Diagrams

5-Pin SOT23/SC70 (LMV7271/LMV7275)



8-Bump micro SMD (LMV7272)

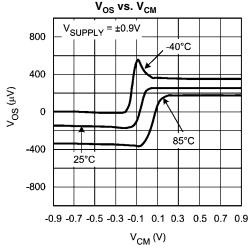


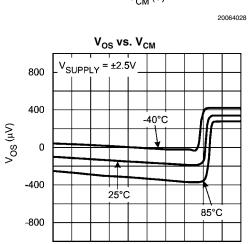
Top View (bump side down)

Ordering Information

Package	Part Number	Package Marking	Transport Media	NSC Drawing	
5-Pin SOT23	OT23 LMV7271MF C25A 1k Units Tape and Reel		1k Units Tape and Reel	MF05A	
	LMV7271MFX	3k Units Tape and Reel			
Γ	LMV7275MF	LMV7275MF C26A 1k Units Tape and Reel			
	LMV7275MFX		3k Units Tape and Reel		
5-Pin SC70	LMV7271MG	C34	1k Units Tape and Reel	MAA05A	
Γ	LMV7271MGX		3k Units Tape and Reel		
Γ	LMV7275MG	C35	1k Units Tape and Reel		
Γ	LMV7275MGX		3k Units Tape and Reel		
8-Bump micro LMV7272TL I 01		250 Units Tape and Reel TLA08.			
SMD	LMV7272TLX		3k Units Tape and Reel		

Typical Performance Characteristics (T_A = 25°C, Unless otherwise specified).





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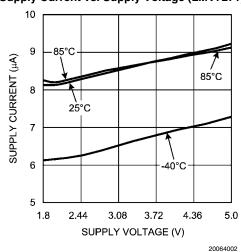
Supply Current vs. Supply Voltage (LMV7271)

0

 $V_{CM}(V)$

-1

-2.5 -2



V_{OS} vs. V_{CM}

800 V_{SUPPLY} = ±1.35V

400 25°C

-400 85°C

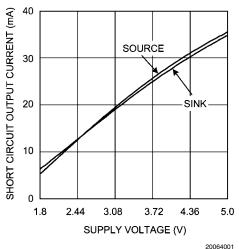
-800 85°C

-1.35 -0.9 -0.45 0 0.45 0.9 1.35

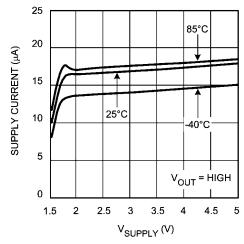
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Short Circuit vs. Supply Voltage

 $V_{CM}(V)$

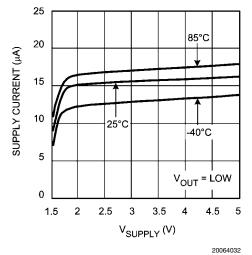


Supply Current vs. Supply Voltage (LMV7272)

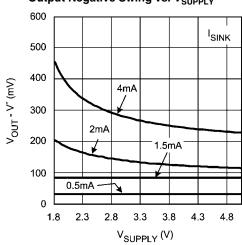


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Supply Current vs. Supply Voltage (LMV7272)

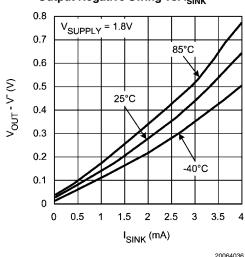


Output Negative Swing vs. V_{SUPPLY}

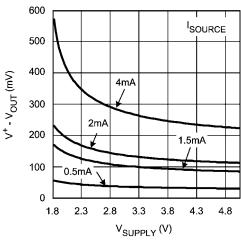


Output Negative Swing vs. I_{SINK}

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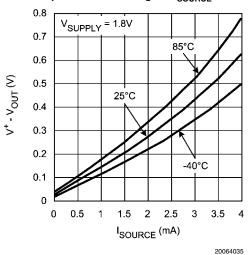


Output Positive Swing vs. V_{SUPPLY}

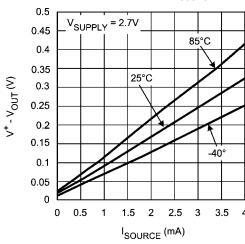


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Output Positive Swing vs. I_{SOURCE}

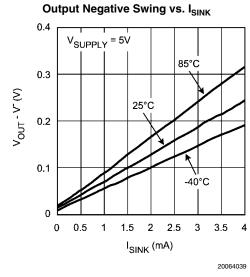


Output Positive Swing vs. I_{SOURCE}



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Output Negative Swing vs. I_{SINK} 0.5 $V_{SUPPLY} = 2.7V$ 0.45 85°C 0.4 0.35 V_{OUT} - V⁻ (V) 0.3 25°C 0.25 0.2 0.15 0.1 -40°C 0.05 0 2 2.5 3 0 0.5 1 1.5 3.5 I_{SINK} (mA)

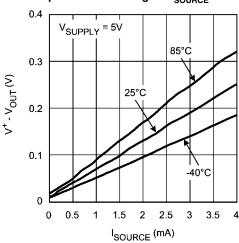


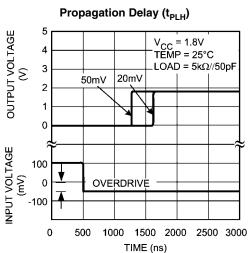
Output Positive Swing vs. I_{SOURCE}

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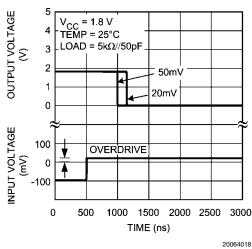
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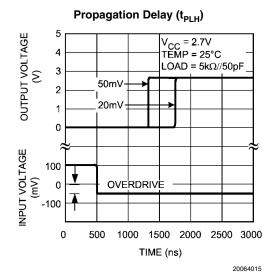




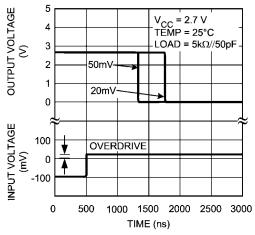
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Propagation Delay (t_{PHL})





Propagation Delay (t_{PHL})



1000 1500 2000

TIME (ns)

0

500

Propagation Delay (t_{PLH})

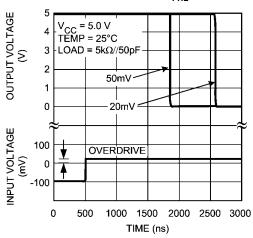
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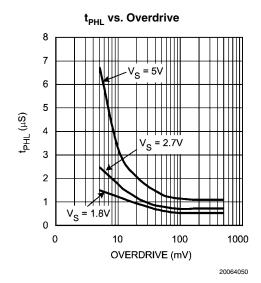
2500 3000

Propagation Delay (t_{PHL})

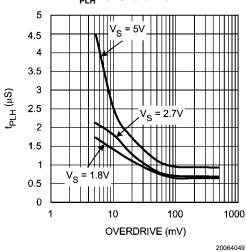
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t_{PLH} vs. Overdrive

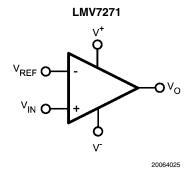


Application Notes

BASIC COMPARATOR

A comparator is often used to convert an analog signal to a digital signal. As shown in *Figure 2*, the comparator compares an input voltage (V_{IN}) to a reference voltage (V_{RFF}) . If V_{IN} is

less than $\rm V_{REF},$ the output (V_O) is low. However, if V_IN is greater than V_REF, the output voltage (V_O) is high.



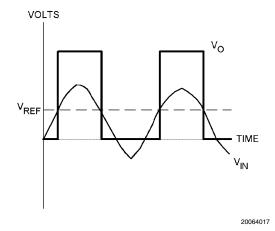


FIGURE 2. LMV7271 Basic Comparator

RAIL-TO-RAIL INPUT STAGE

The LMV727X has an input common mode voltage range (V_{CM}) of -0.1V below the V- to 0.1V above V+. This is achieved by using paralleled PNP and NPN differential input pairs. When the V_{CM} is near V+, the NPN pair is on and the PNP pair is off. When the V_{CM} is near V-, the NPN pair is off and the PNP pair is on. The crossover point between the NPN and PNP input stages is around 950mV from V+. Since each input stage has its own offset voltage (V_{OS}), the V_{OS} of the comparator becomes a function of the V_{CM} . See curves for V_{OS} vs. V_{CM} in Typical Performance Characteristics section. In application design, it is recommended to keep the V_{CM} away from the crossover point to avoid problems. The wide input voltage range makes LMV727X ideal in power supply monitoring circuits, where the comparators are used to sense signals close to ground and power supplies.

OUTPUT STAGE

The LMV7271 and LMV7272 have a push-pull output stage. This output stage keeps the total system power consumption to the absolute minimum. The only current consumed is the low supply current and the current going directly into the load. When the output switches, both PMOS and NMOS at the output stage are on at the same time for a very short time. This allows current to flow directly between V+ and V- through output transistors. The result is a short spike of current (shoot-through current) drawn from the supply and glitches in the supply voltages. The glitches can spread to other parts of the board as noise. To prevent the glitches in supply lines, power supply bypass capacitors must be installed. See section for supply bypassing in the Application Notes for details.

HYSTERESIS

It is a standard procedure to use hysteresis (positive feedback) around a comparator, to prevent oscillation, and to avoid excessive noise on the output because the comparator is a good amplifier of its own noise.

Inverting Comparator with Hysteresis

The inverting comparator with hysteresis requires a three resistor network that is referenced to the supply voltage V_{CC} of the comparator (*Figure 3*). When V_{IN} at the inverting input is less than V_A , the voltage at the non-inverting node of the comparator ($V_{IN} < V_A$), the output voltage is high (for simplicity assume V_O switches as high as V_{CC}). The three network resistors can be represented as $R_1 \| R_3$ in series with R_2 . The lower input trip voltage V_{A1} is defined as

$$V_{A1} = \frac{V_{CC} R_2}{(R_1 || R_3) + R_2}$$

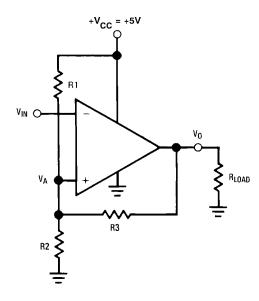
When V_{IN} is greater than V_A ($V_{IN} > V_A$), the output voltage is low and very close to ground. In this case the three network resistors can be presented as $R_2/\!/R_3$ in series with R_1 . The upper trip voltage V_{A2} is defined as

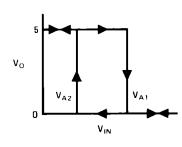
$$V_{A2} = \frac{V_{CC} (R_2 || R_3)}{R_1 + (R_2 || R_3)}$$

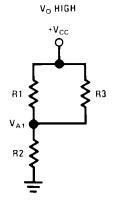
The total hysteresis provided by the network is defined as

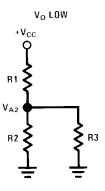
$$\Delta V_A = V_{A1} - V_{A2}$$

A good typical value of ΔV_A would be in the range of 5 to 50mV. This is easily obtained by choosing R_3 as 1000 to 100 times ($R_1 \parallel R_2$) for 5V operation, or as 300 to 30 times ($R_1 \parallel R_2$) for 1.8V operation.









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FIGURE 3. Inverting Comparator with Hysteresis

Non-Inverting Comparator with Hysteresis

A non-inverting comparator with hysteresis requires a two resistor network, and a voltage reference (V_{REF}) at the inverting input (*Figure 4*). When V_{IN} is low, the output is also low. For the output to switch from low to high, V_{IN} must rise up to V_{IN1}, where V_{IN1} is calculated by

$$V_{in1} = \frac{V_{ref}(R_1 + R_2)}{R_2}$$

When V_{IN} is high, the output is also high. To make the comparator switch back to its low state, V_{IN} must equal V_{REF} before V_A will again equal V_{REF} . V_{IN} can be calculated by:

$$V_{in2} = \frac{V_{ref}(R_1 + R_2) - V_{CC}R_1}{R_2}$$

The hysteresis of this circuit is the difference between $\rm V_{IN1}$ and $\rm V_{IN2}.$

$$\Delta V_{IN} = V_{CC}R_1/R_2$$

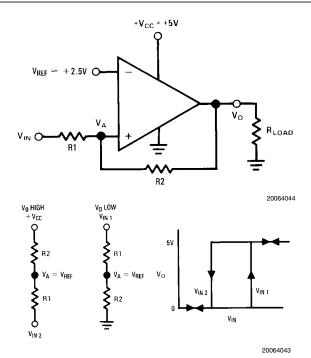


FIGURE 4. Non-Inverting Comparator with Hysteresis

CIRCUIT TECHNIQUES FOR AVOIDING OSCILLATIONS IN COMPARATOR APPLICATIONS

Feedback to almost any pin of a comparator can result in oscillation. In addition, when the input signal is a slow voltage ramp or sine wave, the comparator may also burst into oscillation near the crossing point. To avoid oscillation or instability, PCB layout should be engineered thoughtfully. Several precautions are recommended:

- 1. Power supply bypassing is critical, and will improve stability and transient response. Resistance and inductance from power supply wires and board traces increase power supply line impedance. When supply current changes, the power supply line will move due to its impedance. Large enough supply line shift will cause the comparator to misoperate. To avoid problems, a small bypass capacitor, such as 0.1uF ceramic, should be placed immediately adjacent to the supply pins. An additional 6.8µF or greater tantalum capacitor should be placed at the point where the power supply for the comparator is introduced onto the board. These capacitors act as an energy reservoir and keep the supply impedance low. In dual supply application, a 0.1µF capacitor is recommended to be placed across V+ and V- pins.
- 2. Keep all leads short to reduce stray capacitance and lead inductance. It will also minimize any unwanted coupling from any high-level signals (such as the output). The comparators can easily oscillate if the output lead is inadvertently allowed to capacitively couple to the inputs via stray capacitance. This shows up only during the output voltage transition intervals as the comparator changes states. Try to avoid a long loop which could act as an inductor (coil).
- 3. It is a good practice to use an unbroken ground plane on a printed circuit board to provide all components with a low inductive ground connection. Make sure ground paths are

- low-impedance where heavier currents are flowing to avoid ground level shift. Preferably there should be a ground plane under the component.
- 4. The output trace should be routed away from inputs. The ground plane should extend between the output and inputs to act as a guard. This can be achieved by running a topside ground plane between the output and inputs. A typical PCB layout is shown in Figure 5.

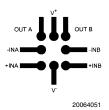


FIGURE 5. Typical PCB Layout

- 5. When the signal source is applied through a resistive network to one input of the comparator, it is usually advantageous to connect the other input with a resistor with the same value, for both DC and AC consideration. Input traces should be laid out symmetrically if possible.
- 6. All pins of any unused comparators should be tied to the negative supply.

micro SMD LIGHT SENSITIVITY

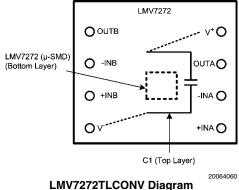
Exposing the micro SMD device to direct sunlight will cause mis-operation of the device. Light sources such as Halogen lamps can also affect electrical performance if brought near to the device. The wavelengths, which have the most detrimental effect, are reds and infrareds.

micro SMD MOUNTING

The micro SMD package requires specific mounting techniques, which are detailed in National Semiconductor Application Note AN-1112.

LMV7272 micro SMD to DIP Conversion Board

To facilitate characterization and testing, a micro SMD to DIP conversion board, LMV7272TLCONV, is available. It is a 2layer board, with the LMV7272 mounted on the bottom layer, and a capacitor (C1, between the positive and negative supplies) added to the top layer.



Typical Applications

UNIVERSAL LOGIC LEVEL SHIFTER

The output of LMV7275 is an unconnected drain of an NMOS device, which can be pulled up, through a resistor, to any desired output level within the permitted power supply range. Hence, the following simple circuit works as a universal logic level shifter, pulling up the signal to the desired level.

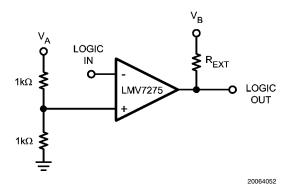


FIGURE 6. Logic Level Shifter

POSITIVE PEAK DETECTOR

A positive peak detect circuit is basically a comparator operated in a unity gain follower configuration, with a capacitor as a load to maintain the highest voltage. A diode is added at the output to prevent the capacitor from discharging through the pull-up resistor, and a $1 M \Omega$ resistor added in parallel to the capacitor to provide a high impedance discharge path. When the input V_{IN} increases, the inverting input of the comparator follows it, thus charging the capacitor. When it decreases, the cap discharges through the $1 M \Omega$ resistor. The decay time can be modified by changing the resistor. The output should be accessed through a follower circuit to prevent loading.

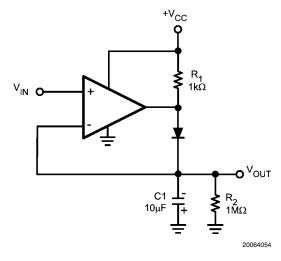


FIGURE 7. Positive Peak Detector

OR'ING THE OUTPUT

Since the output is an unconnected NMOS drain, many drains can be tied together, pulled up to V_{DD} by a single resistor to provide an output OR'ing function. If any of the comparator outputs is pulled low the output V_{O} goes down.

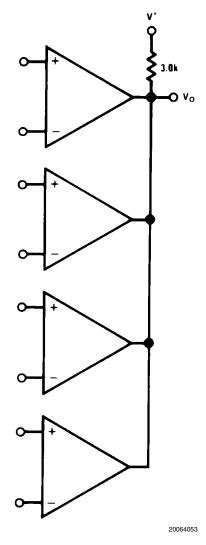


FIGURE 8. OR'ing the Outputs

NEGATIVE PEAK DETECTOR

For the negative detector, the output transistor of the comparator acts as a low impedance current sink. Since there is no pull-up resistor, the only discharge path will be the $1 M \Omega$ resistor and any load impedance used. Decay time is changed by varying the $1 M \Omega$ resistor.

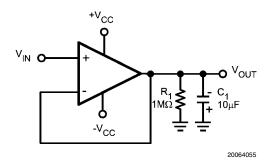
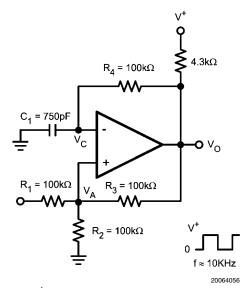
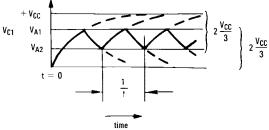


FIGURE 9. Negative Peak Detector

SQUARE WAVE GENERATOR

A typical application for a comparator is as a square wave oscillator. The circuit below generates a square wave whose period is set by the RC time constant of the capacitor C_1 and resistor R_4 . The maximum frequency is limited by the large signal propagation delay of the comparator, and by the capacitive loading at the output, which limits the output slew rate.





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FIGURE 10. Squarewave Oscillator

To analyze the circuit, consider it when the output is high. That implies that the inverted input (V_C) is lower than the non-inverting input (V_A) . This causes the C_1 to get charged through R_4 , and the voltage V_C increases till it is equal to the non-inverting input. The value of V_Δ at this point is

$$V_{A1} = \frac{V_{CC}.R_2}{R_2 + R_1||R_3}$$

If
$$R_1 = R_2 = R_3$$
 then $V_{A1} = 2V_{CC}/3$

At this point the comparator switches pulling down the output to the negative rail. The value of $V_{\rm A}$ at this point is

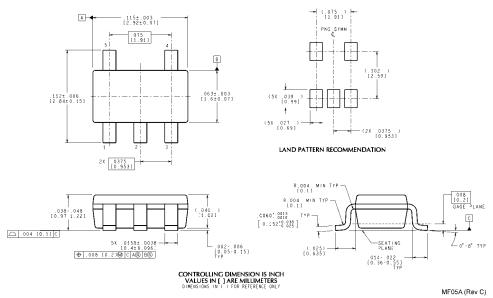
$$V_{A2} = \frac{V_{CC}(R_2||R_3)}{R_1 + (R_2||R_3)}$$

If
$$R_1 = R_2 = R_3$$
 then $V_{A2} = V_{CC}/3$

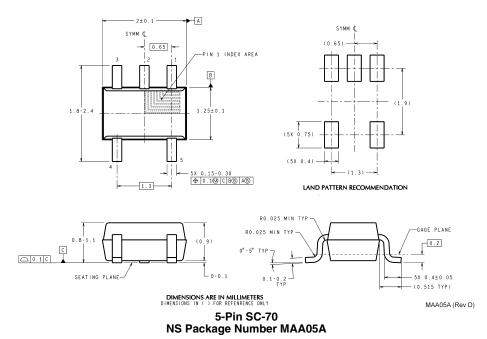
The capacitor C_1 now discharges through R_4 , and the voltage V_C decreases till it is equal to V_{A2} , at which point the comparator switches again, bringing it back to the initial stage. The time period is equal to twice the time it takes to discharge C_1 from $2V_{CC}/3$ to $V_{CC}/3$, which is given by R_4C_1 .In2. Hence the formula for the frequency is:

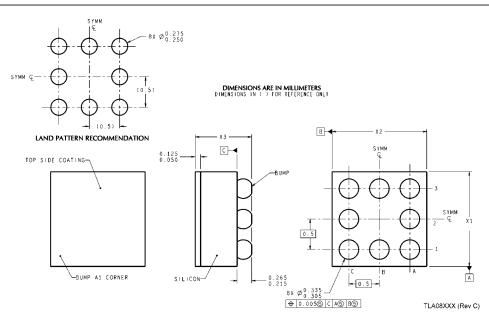
$$F = 1/(2 \cdot R_4 \cdot C_1 \cdot ln2)$$

Physical Dimensions inches (millimeters) unless otherwise noted



5-Pin SOT-23 NS Package Number MF05A





NOTE: UNLESS OTHERWISE SPECIFIED

- 1. EPOXY COATING
- 2. 63Sn/37Pb EUTECTIC BUMP
- 3. RECOMMEND NON-SOLDER MASK DEFINED LANDING PAD.
- 4. PIN A1 IS ESTABLISHED BY LOWER LEFT CORNER WITH RESPECT TO TEXT ORIENTATION REMAINING PINS ARE NUMBERED COUNTERCLOCKWISE.
- 5. XXX IN DRAWING NUMBER REPRESENTS PACKAGE SIZE VARIATION WHERE X1 IS PACKAGE WIDTH, X2 IS PACKAGE LENGTH AND X3 IS PACKAGE HEIGHT.
- 6. REFERENCE JEDEC REGISTRATION MO-211, VARIATION BC.

Notes

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